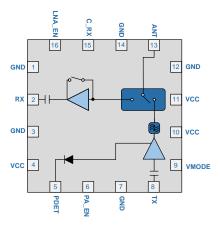


# **RFFM8505**

## 4.9GHz to 5.85GHz 802.11a/n/ac WiFi Front End Module

The RFFM8505 provides a complete integrated solution in a single front end module (FEM) for WiFi 802.11a/n/ac systems. The ultra-small factor and integrated matching minimizes layout area in the customer's application and greatly reduces the number of external components. This simplifies the total front end solution by reducing the bill of materials, system footprint, and manufacturing cost. The RFFM8505 integrates a 5 GHz power amplifier (PA), single pole double throw switch (SP2T), LNA with bypass, and a power detector coupler for improved accuracy. The device is provided in a 2.5mm x 2.5mm x 0.40mm, 16pin QFN package. This module meets or exceeds the RF front end needs of IEEE 802.11a/n/ac WiFi RF systems.



Functional Block Diagram

## **Ordering Information**

•	
RFFM8505SB	Standard 5-piece sample bag
RFFM8505SQ	Standard 25-piece sample bag
RFFM8505SR	Standard 100-piece reel
RFFM8505TR7	Standard 2500-piece reel
RFFM8505PCK-410	Fully assembled evaluation board w/ 5-piece bag



## Package: QFN, 16-pin, 2.5mm x 2.5mm x 0.40mm

### Features

- P<sub>OUT</sub>=17.5dBm, 11ac, 80MHz
  1.5% (-36.5dB) EVM
- P<sub>OUT</sub>=19.5dBm, 11n 20MHz
  2.5% (-32dB) EVM
- Input and Output Matched to 50Ω
- Integrated 5GHz PA, SP2T Switch, LNA, and PDET
- Low Height Package, Suited for SiP and CoB designs
- Supports low power mode for improved efficiency

## **Applications**

- Cellular Handsets
- Mobile Devices
- Tablets
- Consumer Electronics
- Gaming
- Netbooks/Notebooks
- TV/Monitors/Video

RF Micro Devices Inc. 7628 Thorndike Road, Greensboro, NC 27409-9421

For sales or technical support, contact RFMD at +1.336.678.5570 or customerservice@rfmd.com.

DS131106

RF MICRO DEVICES<sup>®</sup> and RFMD<sup>®</sup> are trademarks of RFMD, LLC. BLUETOOTH is a trademark owned by Bluetooth SIG, Inc., U.S.A. and licensed for use by RFMD. All other trade names, trademarks, and registered trademarks are the property of their respective owners. ©2013, RF Micro Devices, Inc.



## **Absolute Maximum Ratings**

Parameter	Rating	Unit
DC Supply Voltage (No RF Applied)	6	V
PA Enable Voltage	-0.5 to 5	V <sub>DC</sub>
DC Supply Current	500	mA
Operating Temperature Range	-40 to +85	°C
Storage Temperature	-40 to +150	°C
Maximum TX Input Power into $50\Omega$ Load for 11a/n/ac (No Damage)	+12	dBm
LNA On Maximum RX input power (No damage)	+12	dBm
Bypass Mode Maximum RX input power (No damage)	+25	dBm
Moisture Sensitivity	MSL2	





RFMD Green: RoHS status based on EU Directive 2011/65/EU (at time of this document revision), halogen free per IEC 61249-2-21, < 1000pm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

## **Nominal Operating Parameters**

Parameter	Specification			Unit	Condition	
Farameter	Min	Тур	Max	Unit	Condition	
Compliance					802.11a, 802.11n, 802.11ac	
Operating Frequency	5.15		5.825	GHz		
Extended Frequency	4.9		5.85	GHz	Functional with reduced performance -3dB lower TX power	
Operating Temperature	-10		70	°C		
Extended Operating Temperature	-40		85	°C	Functional with reduced performance	
Power Supply V <sub>cc</sub>	3.2	3.6	4.6	V		
Extended V <sub>CC</sub>	3		5.0	V	Please see 5 volts apps schematic	
Control Voltage-high	2.8	3.1	Vcc	V	PA_EN, C_RX, LNA_EN, V <sub>MODE</sub> . Should not exceed V <sub>CC</sub> voltage	
Control Voltage-low		0	0.4	V		
Transmit (TX-ANT) High Power					T= -10°C to +70°C, V <sub>cc</sub> =3.2V to 4.6V,	
Mode					50% Duty Cycle unless otherwise noted	
HT80 Output Power	17.0	17.5		dBm	$T= 25^{\circ}C, V_{CC}= 3.6V$	
80MHz 802.11ac - Dynamic EVM		1.5	1.8	%		
		-36.5	-35.0	dB		
HT80 Output Power		16.0		dBm	T= -10°C to +70°C, V <sub>CC</sub> =3.2V to 4.6V	
80MHz 802.11ac - Dynamic EVM		1.5	1.8	%		
		-36.5	-35.0	dB		
HT20 Output Power	19.0	19.5		dBm	T= 25°C, V <sub>CC</sub> = 3.6V	
20MHz 802.11n - Dynamic EVM		2.5	3	%		
·		-32	-30.5	dB		
HT20 Output Power		18.0		dBm	T= -10°C to +70°C, V <sub>CC</sub> =3.2V to 4.6V	
20MHz 802.11n - Dynamic EVM		2.5	3	%		
		-32	-30.5	dB		
20/80MHz 802.11ac - Spectral Mask		22		dBm	T= 25°C, V <sub>cc</sub> = 3.6V	
40MHz 802.11n - Spectral Mask		21		dBm		
TX Port Return Loss	10	18		dB		
ANT Port Return Loss	10	18		dB		
Large Signal Gain	24	28	31	dB	T= 25°C, V <sub>CC</sub> = 3.6V	
	23	28	31	dB	T= -10°C to +70°C, V <sub>CC</sub> =3.2V to 4.6V	
Gain flatness over any 80MHz BW	-0.5		0.5	dB		

RF Micro Devices Inc. 7628 Thorndike Road, Greensboro, NC 27409-9421

For sales or technical support, contact RFMD at +1.336.678.5570 or customerservice@rfmd.com.

The information in this publication is believed to be accurate. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents or other rights of third parties resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

DS131106

## **RFFM8505**



	Specification				Condition	
Parameter	Min Typ Max		Unit			
Transmit (TX-ANT) High Power Mode (continued)					T= -10°C to +70°C, VCC=3.2V to 4.6V, 50% Duty Cycle unless otherwise noted	
Gain flatness across band	-1		1	dB		
Operating Current		230		mA	P <sub>OUT</sub> = 17.5dBm, T= 25°C, V <sub>CC</sub> = 3.6V	
		215	270	mA	P <sub>OUT</sub> = 16dBm, T= -10 to +70C, V <sub>CC</sub> =3.2V to 4.6V	
		260		mA	P <sub>OUT</sub> = 19.5dBm, T= 25°C, V <sub>CC</sub> = 3.6V	
		235	300	mA	$P_{OUT}$ = 18dBm, T= -10 to +70C, $V_{CC}$ =3.2V to 4.6V	
Quiescent current		165		mA	RF= Off, T= 25°C, V <sub>CC</sub> = 3.6V	
PA_EN Current		70	150	uA		
Second Harmonic		-45	-40	dBm/MHz	P <sub>OUT</sub> = 18dBm, T= 25°C, V <sub>CC</sub> = 3.6V, 6Mbps 802.11a	
Third Harmonic		-45	-38	dBm/MHz		
Power Detector Voltage	0.28	0.32	0.37	V	$P_{OUT}=0$ dBm, T= 25°C	
Power Detector Nominal 5210MHz	0.75		0.95	V	P <sub>OUT</sub> = 17.5dBm, T= 25°C, V <sub>CC</sub> = 3.6V	
Power Detector Nominal 5775MHz	0.7		0.88	V		
Power Detector Voltage	0.8	0.95	1.2	V	P <sub>OUT</sub> = 20dBm	
Variation from 0-360° load pull	-1.5		1.5	dB	3:1 VSWR	
ANT-RX Isolation (TX Mode-TX enabled and maximum power)		28		dB		
Transmit (TX-ANT) Low Power					T= 25°C, V <sub>CC</sub> = 3.6V,50% Duty Cycle	
Mode					unless otherwise noted	
HT80 Output Power		11.0		dBm	$T = 25^{\circ}C, V_{CC} = 3.6V$	
80MHZ 802.11ac Dynamic EVM		1.5	1.8	%		
		-36.5	-35.0	dB		
HT20 Output Power		13.0		dBm	$T = 25^{\circ}C, V_{CC} = 3.6V$	
20MHz 802.11n Dynamic EVM		2.5	3	%		
-		-32.0	-30.5	dB		
TX Performance – Spectral Mask						
40MHz 802.11n Output Power		12		dBm	$T = 25^{\circ}C, V_{CC} = 3.6V$	
20/ 80MHz 802.11ac Output Power		14		dBm	1	
Operating Current		150	180	mA	P <sub>out</sub> = 11dBm for 11ac	
		170	200	mA	P <sub>OUT</sub> = 13dBm for 11n	
V <sub>MODE</sub> Control Line Current		160	500	μA		
Large Signal Gain		25		dB	P <sub>OUT</sub> = 12dBm	
Large Signal Gain	23	25		dB	T= -10 to +70C, V <sub>CC</sub> =3.2V to 4.6V	
Gain flatness over any 80MHz BW	-0.5		0.5	dB		

RF Micro Devices Inc. 7628 Thorndike Road, Greensboro, NC 27409-9421 For sales or technical support, contact RFMD at +1.336.678.5570 or customerservice@rfmd.com. DS131106



Devenue ( en	Specification			11-14	Condition	
Parameter	Min	Тур	Max	Unit	Condition	
Receive (ANT-RX)-LNA On					Freq = 5.15GHz to 5.825GHz, T = -10°C to +70°C, V <sub>cc</sub> =3.2V to 5.0V, unless otherwise noted.	
Gain	9	12	15	dB	$T = 25^{\circ}C, V_{CC} = 3.6V$	
	8	12	16	dB		
Gain flatness over any 80MHz BW	-0.5		0.5	dB	$T=25^{\circ}C, V_{CC}=3.6V$	
Gain flatness across band	-1		1	dB		
Noise Figure		2.5	3	dB	$T = 25^{\circ}C, V_{CC} = 3.6V$	
		2.5	3.5	dB		
Rx Port Return Loss	10	20		dB		
ANT Port Return Loss	10	15		dB		
Nominal Input P1dB	-5	-3		dBm	$T= 25^{\circ}C, V_{CC}= 3.6V$	
Current Consumption		10	16	mA		
LNA_EN Control Current		130	200	μA		
LNA Turn On Time		400	600	nS		
Receive (ANT-RX)-Bypass Mode					T= -10°C to +70°C, V <sub>CC</sub> = 3.2V to 5.0V, unless otherwise noted	
LNA Bypass Current		0.5		μA		
Nominal Insertion Loss	5	8	11	dB	$T = 25^{\circ}C, V_{CC} = 3.6V$	
RX Port Return Loss	8	15		dB		
ANT Port Return Loss	10	20		dB		
Nominal Input P1dB	15	20		dBm	$T= 25^{\circ}C, V_{CC}= 3.6V$	
General Specifications						
Control Line Impedance-PA_EN		75		kΩ		
Control Line Impedance-LNA_EN		78		kΩ		
Control Line Impedance-C_RX		27		MΩ		
Switch Control Current – High - Each Line		5	100	μA		
Switch Control Current – Low - Each Line		0.5	2	μA		
Switching Speed		100	500	ns		
ESD – Human Body Model		1000		V		
PA Turn-on Time		200	500	ns	10% to 90%	
PA Stability			20	dBm	No spurious above -41.25dBm/MHz	
Maximum Input Power			12	dBm	Into 50Ω, V <sub>CC</sub> = 3.3V, 25°C	
			12	dBm	6:1 VSWR, V <sub>CC</sub> = 3.3V, 25°C	
			5	dBm	10:1 VSWR, V <sub>CC</sub> = 3.3V, 25°C	
Leakage Current	0	2	10	uA	V <sub>CC</sub> = 4.8V, T= 25°C, RF OFF, All control lines floating	
Transmit (TX-ANT) High Power Mode at 5V					Freq = 5.15GHz to 5.825GHz, V <sub>CC</sub> = 5.0V, T= +25°C, 50% Duty Cycle, unless otherwise noted.	
		10.0		dDree		
Output Power		19.0	10	dBm	T= 25°C, V <sub>CC</sub> = 5.0V	
80MHz 802.11ac Dynamic EVM		1.5	1.8	% dD		
Output Dower		-36.5	-35.0	dB		
Output Power		20	<u>^</u>	dBm	T= 25°C, V <sub>CC</sub> = 5.0V	
20MHz 802.11n Dynamic EVM	<b>—</b>	2.5 -32.0	3 -30.5	% dB		
Large Signal Gain	23	28		dB		
Operation Current		270		mA	P <sub>OUT</sub> = 19dBm	
		285		mA	P <sub>OUT</sub> = 20dBm	
Quiescent current		200		mA	RF = Off	

RF Micro Devices Inc. 7628 Thorndike Road, Greensboro, NC 27409-9421

DS131106

For sales or technical support, contact RFMD at +1.336.678.5570 or customerservice@rfmd.com.



## Switch Control Logic Truth Table

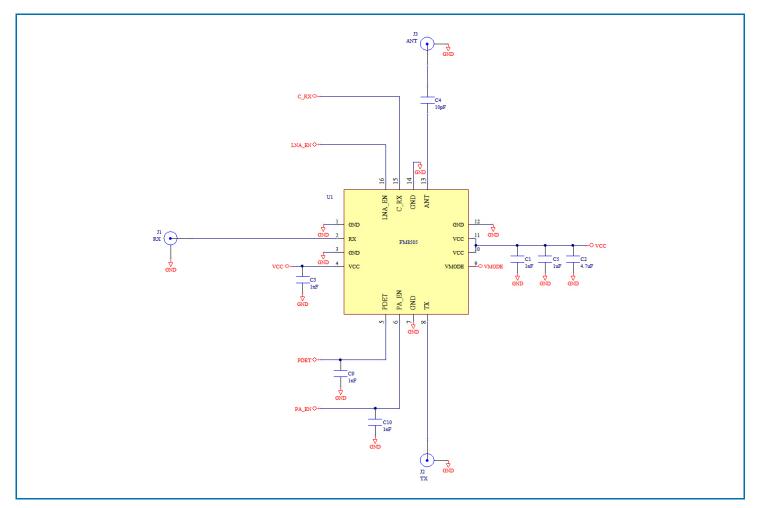
Operating Mode	PA_EN	LNA_EN	C_RX	V <sub>MODE</sub>
Standby	Low	Low	Low	Low
802.11a/n/ac TX High Power	High	Low	Low	Low
802.11a/n/ac TX Low Power	High	Low	Low	High
802.11a/n/ac RX Gain	Low	High	High	Low
802.11a/n/ac RX Bypass	Low	Low	High	Low

Notes:

• PA\_EN and TX switch control are tied together internally.

• High = 2.8 to V<sub>CC</sub>. Low = 0V to 0.2V

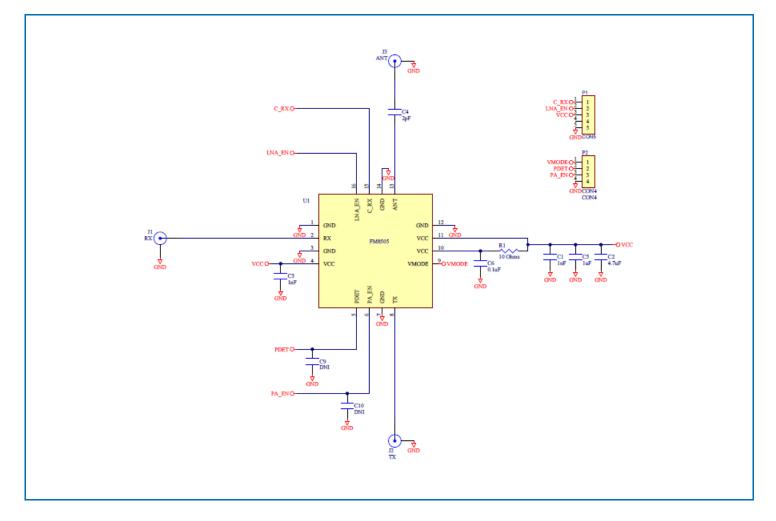
## **Evaluation Board Schematic**



DS131106

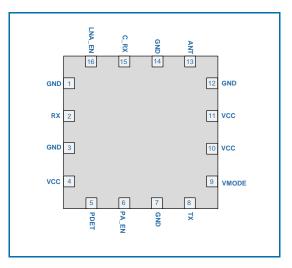


## **5V Evaluation Board Schematic**

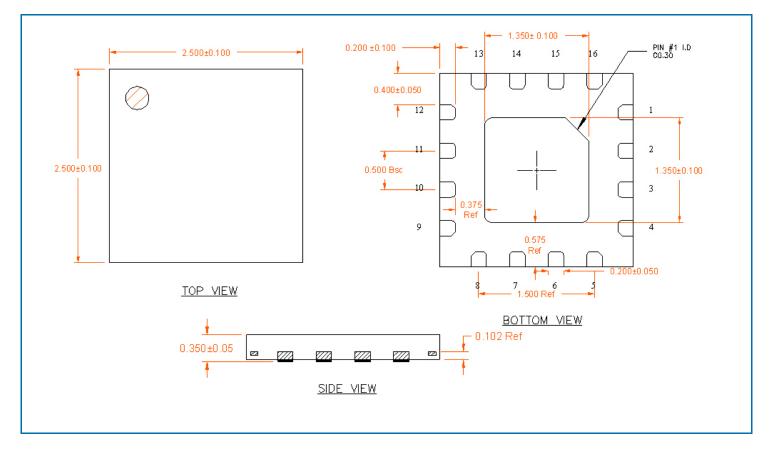








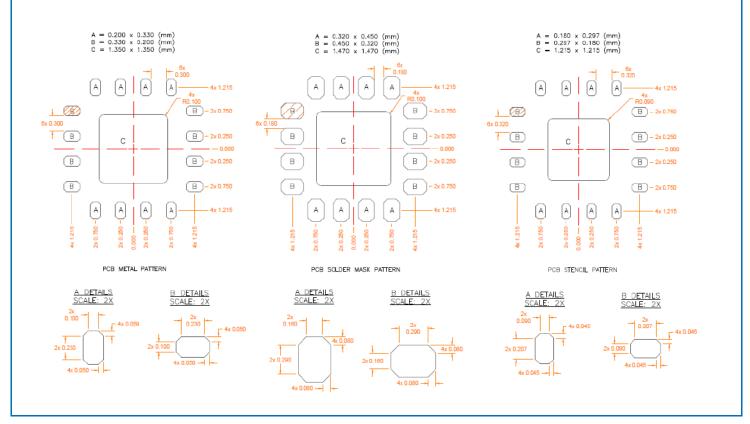
## Package Outline and Branding Drawing (Dimensions in millimeters)



DS131106



## **PCB Patterns**



#### Notes:

1. Thermal vias for center slug "C" should be incorporated into the PCB design. The number and size of thermal vias will depend on the application, power, dissipation and electrical requirements. Example of the number and size of vias can be found on the RFMD evaluation board layout (gerber files are available upon request)



## **Pin Names and Descriptions**

Pin	Name	Description					
1	GND	Ground connection. This pin is not connected internally and can be left floating or connected to ground.					
2	RX	RF output port for the 802.11a/n/ac LNA. This port is matched to $50\Omega$ and DC blocked internally.					
3	GND	This pin is not connected internally and can be left floating or connected to ground.					
4	VCC	Supply voltage for the LNA and PA Regulator. See applications schematic for biasing and bypassing components.					
5	PDET	Power detector voltage for the TX path. May need external series R/shunt C to adjust voltage level and to filter RF noise.					
6	PA_EN	Control voltage for the PA and TX switch. See truth table for proper settings.					
7	GND	This pin is not connected internally and can be left floating or connected to ground.					
8	тх	RF input port for the 802.11a/n/ac PA. Input is matched to $50\Omega$ and DC blocked internally					
9	VMODE	High/Low power mode control signal. $V_{MODE}$ can be low or floating for nominal conditions (high power mode). Applying 2.8V or greater to this pin enables low power mode.					
10	VCC	Supply voltage for the first and second stage of the PA. See applications schematic for biasing and bypassing components.					
11	VCC	Supply voltage for the final stage of the PA. See applications schematic for biasing and bypassing components.					
12	GND	This pin is not connected internally and can be left floating or connected to ground.					
13	ANT	RF bidirectional antenna port matched to $50\Omega$ . An External DC block is required					
14	GND	This pin is not connected internally and can be left floating or connected to ground.					
15	C_RX	Receive switch control pin. See switch truth table for proper level.					
16	LNA_EN	Control voltage for the LNA. When this pin is set to a LOW logic state, the bypass mode is enabled.					
Pkg Base	GND	Ground connection. The backside of the package should be connected to the ground plane through a short path, i.e., PCB vias under the device are recommended.					